Thyristor Semiconductor Device - Page 1 of 1



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# Inclosure Material:

Metal

## Overall Length:

Between 0.330 inches and 0.505 inches

## Mounting Facility Quantity:

1

## Electrode Internally-electrically Connected To Case:

Anode

## **Mounting Method:**

Threaded stud

### **Overall Width Across Flats:**

Between 0.544 inches and 0.562 inches

**Thread Size:** 

0.250 inches

Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

200.0 breakover voltage, dc

## **Current Rating Per Characteristic:**

125.00 amperes forward current, average absolute

## Power Rating Per Characteristic:

500.0 milliwatts small-signal input power, common-collector blank

## Maximum Operating Tempurature Per Measurement Point:

105.0 degrees celsius case

## **Thread Series Designator:**

Unf

### **Terminal Type And Quantity:**

2 tab, solder lug and 1 threaded stud

Shelf Life:

N/a

### Unit Of Measure:

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# Demilitarization:

No

### Fiig:

A110a0